# -60V -4A P-Channel Enhancement Mode Power MOSFET

#### Features

- Advanced trench technology
- Excellent RDS(ON) and Low Gate Charge
- Lead free product is acquired

### SYMBOL





Application

PWM Application

Power management

· Load Switch

SOT-23

#### ASSEMBLY MESSAGE

Product Name	Package	Packaging
BXT1700P06M	SOT-23	Reel

#### ABSOLUTE MAXIMUM RATINGS (Tc=25°C unless otherwise noted)

Parameter		Symbol	Rating	Unit	
			SOT-23		
Drain-Source Voltage		VDSS	-60	V	
Drain Current	Continuous (T <sub>c</sub> = 25°C)	- I <sub>D</sub> -	-4	А	
	Continuous (T <sub>c</sub> = 100°C)	ID	-2.8	А	
Drain Current	Pulsed (Note1)	Ідм	-16	А	
Single Pulsed Avalanche Energy		EAS	4.5	mJ	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V	
Power Dissipation T <sub>c</sub> =25°C		PD	1.5	W	
Maximum Junction Temperature		TJ	150	°C	
Storage Temperature Range		Tstg	-55 to 150	°C	

Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature

#### THERMAL CHARACTERISTICS

Parameter	Svmbol	Max.	Unit	]
Faranieter Symbol	Symbol	SOT-23	Onit	
Thermal Resistance, Junction-to-Ambient	Reja	83.3	°C / W	



# BXT1700P06M

#### **ELECTRICAL CHARACTERISTICS** (TJ=25°C, unless otherwise Noted)

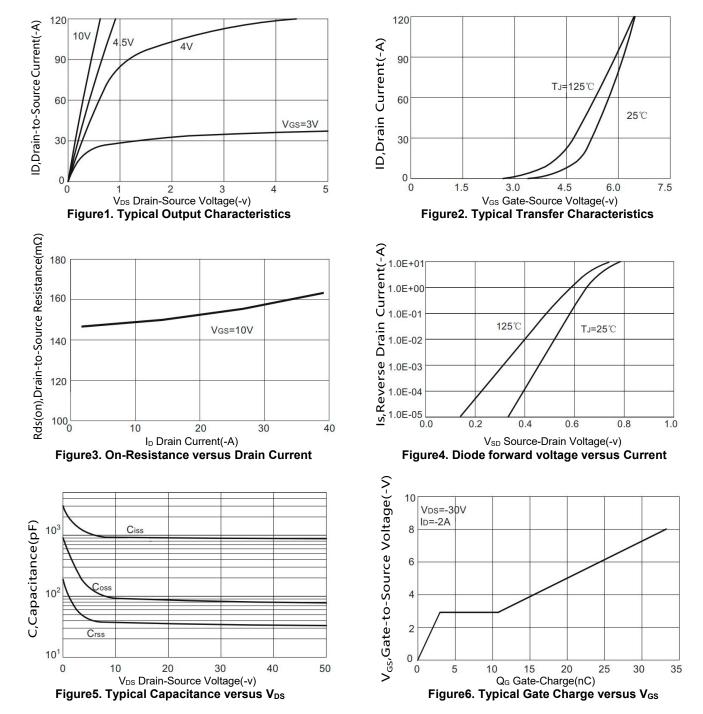
Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
OFF CHARACTERISTICS	•					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	VGS=0V, ID=-250µA	-60			V
Zero Gate Voltage Drain Current	IDSS	VDS=-60V, VGS=0V			-1	uA
Gate-Body Leakage Current, Forward		VGS=20V			1	uA
Gate-Body Leakage Current, Reverse	lgss	VGS=-20V			-1	uA
ON CHARACTERISTICS						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	VDS=VGS, ID=-250µA	-1.5		-3.0	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	VGS=-10V, ID=-2A		140	170	mΩ
DYNAMIC PARAMETERS						
Input Capacitance	CISS			910		pF
Output Capacitance	Coss	VDS=-30V, VGS=0V, f=1.0MHz		82		pF
Reverse Transfer Capacitance	CRSS			35		pF
SWITCHING PARAMETERS						
Turn-ON Delay Time	t <sub>D(ON)</sub>			9		ns
Turn-ON Rise Time	t <sub>R</sub>	VDD=-30V, ID=-2A, VGS		5		ns
Turn-OFF Delay Time	$t_{D(OFF)}$	= -10V, RG=7.5Ω		30		ns
Turn-OFF Fall-Time	t <sub>F</sub>			6		ns
Total Gate Charge(Note2)	$Q_{G}$			22		nC
Gate Source Charge	Q <sub>GS</sub>	VDS =-30V, VGS =-10V, ID=-2A		3		nC
Gate Drain Charge	$Q_{GD}$			7		nC
SOURCE- DRAIN DIODE RATINGS	AND CHAR	ACTERISTICS				
Drain-Source Diode Forward Voltage	Vsd	Is=-4A, VGS=0V			-1.5	V
Diode Continuous Forward Current	ls				-4	А
Maximum Pulsed Drain to Source Diode Forward Current	lsм				-16	A

Note: 2. Essentially independent of operating temperature



## BXT1700P06M

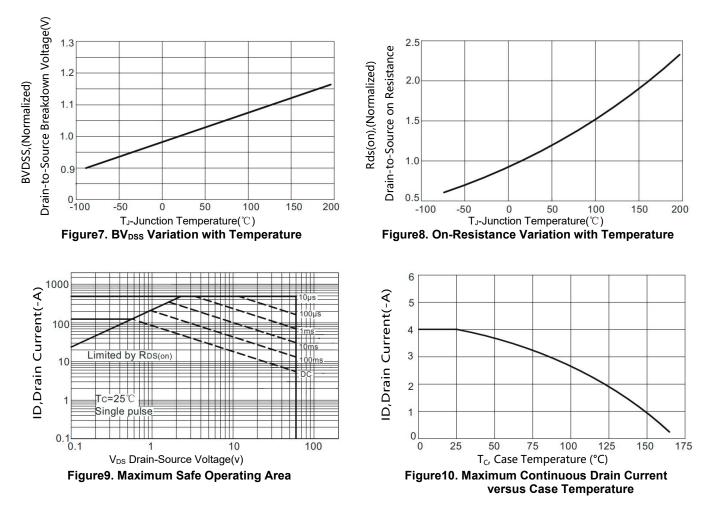
### **TYPICAL CHARACTERISTICS**





## BXT1700P06M

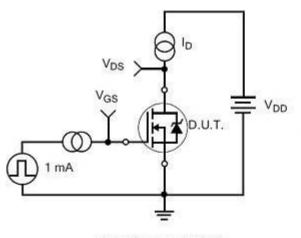
# TYPICAL CHARACTERISTICS(Cont.)



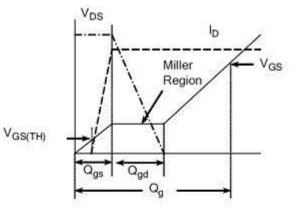


## BXT1700P06M

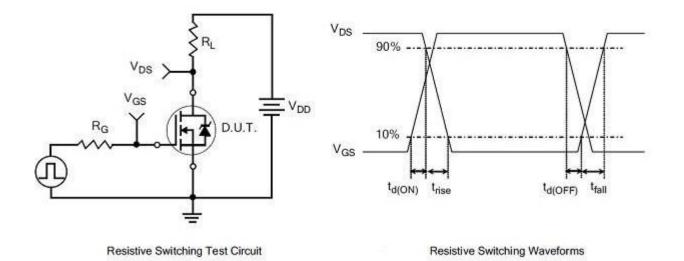
## **TEST CIRCUITS AND WAVEFORMS**



Gate Charge Test Circuit



Gate Charge Waveform



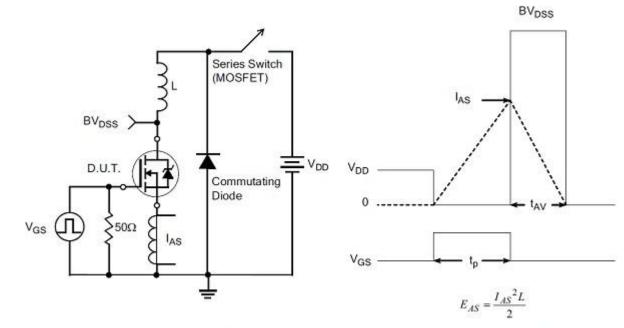


# TEST CIRCUITS AND WAVEFORMS(Cont.)

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Diode Reverse Recovery Test Circuit

Diode Reverse Recovery Waveform



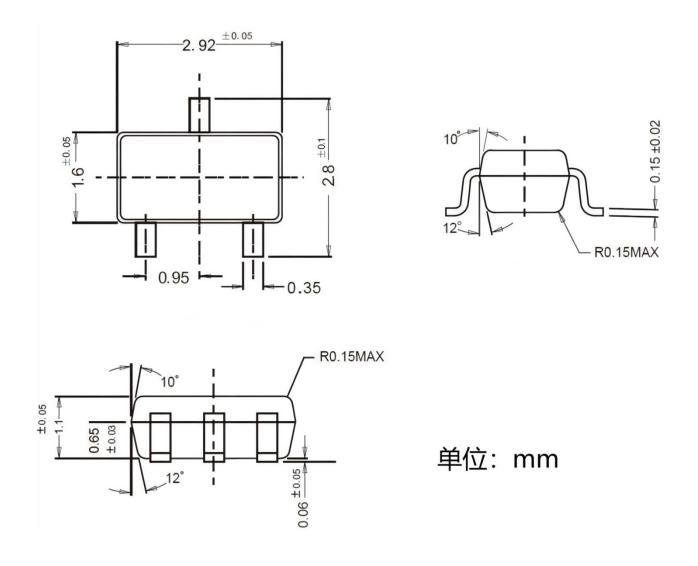
Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms



# BXT1700P06M

SOT-23 Package





# **Revision history**

# Document revision history

Date	Revision	Changes
29-Oct-2021	1.0	First release
10-Jan-2022	1.1	Update parameter



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